

Comment on "Density of states and reflectionless tunneling in NS junction with a barrier"

In a recent paper Schechter, Imry and Levinson (cond-mat/9709248) [1] analysed the density-of-states (DOS) and the conductance of a superconductor-normal metal (S/N) junction with a barrier. They showed that the DOS in the N conductor near the barrier is strongly affected by the superconductor if the energy ϵ is small: $l_n\sqrt{\epsilon/D}\ll\Gamma\ll 1$, where l_n is the mean free path, D is the diffusion constant, and Γ is the barrier transmittance. We would like to note that this problem was analysed in several papers with the use of different approaches. In particular, the author has calculated the DOS and the conductance of S/N structures with a barrier using quasiclassical matrix Green's function technique well developed in the theory of superconductivity [2]. It was shown that in an one-dimensional S/N structure a pseudogap appears in the N conductor near the S/N interface, and the DOS approaches it's normal value at energies ϵ exceeding a characteristic energy ϵ_N related to the interface transmittance; here $\epsilon_N = D/(2R_b\sigma)^2$, R_b is the interface resistance per unit area, and σ is the specific conductivity of the N conductor. In a planar S/N junction a real gap ϵ_N appears in the excitation spectrum of the N electrode. It was shown that peculiarities in the DOS at small energies lead to a subgap conductance at zero temperature. This subgap conductance is caused by a component of the current which is known in the theory of the Josephson effect as the interference component of the Josephson current. An applied magnetic field suppresses the subgap conductance [3]. Therefore, the results for the DOS and the conductance in Ref [1] are similar to the ones obtained earlier, but their interpretation of the subgap conductance differs from that given in Ref. [2] because they use another approach (Landauer formula) for the calculation of the conductance .

In the last years many papers have been published in which the conductance of mesoscopic S/N structures was studied. Two approaches were used in these works. One of them is based on the calculation of a scattering matrix and on the Landauer formula. The other employs the method of matrix quasiclassical Green's functions well developed in the theory of superconductivity (see review articles [4,5]). In Ref. [2] the DOS and the conductance of S/N junctions have been calculated on the basis of the Green's function technique. Both one-dimensional and planar structures have been analysed under assumption that a barrier exists at the interface. It was shown that in the case of a one-dimensional S/N structure a pseudogap appears in the N conductor near the S/N interface, i.e. the DOS increases with increasing energy ϵ and approaches it's value in the normal state (in the absence of the superconductor) at energies much larger than ϵ_N . It was supposed also that the barrier strength is high enough so that the condition $\epsilon_N\ll\Delta$ is satisfied. This result agrees with that obtained in Ref. [1]. In planar S/N junction the DOS is zero in the N electrode at energies $\epsilon < \epsilon_N$ (a real energy gap). Using equations for matrix quasiclassical Green's functions with boundary conditions at the S/N interface [6-8], we have calculated the conductance of these structures and showed

that a subgap conductance appears at zero temperature. The differential conductance dI/dV has a peak at zero bias in a one-dimensional S/N structure and the width of this peak is about ϵ_N/e . In the case of a planar S/N structure this peak is located at ϵ_N/e . The subgap conductance and a dip in the DOS at small energies are related to an anomalous proximity effect at small energies (perhaps Zaitsev was the first who obtained the subgap conductance in a short S/N/N' structure [9,10]). The condensate amplitude F_N in the N conductor near the interface is of the order of the condensate amplitude in the superconductor if the energy is small enough: $\epsilon < \epsilon_N$. In the Green's function technique the appearance of the subgap conductance may be explained as a contribution of a component of the current which is proportional to F_N and is known in the theory of the Josephson effect as the interference component of the Josephson current. A small magnetic field suppresses the subgap conductance [3,10]. Therefore, both phenomena (peculiarities in the DOS at small energies in the N conductor and the subgap conductance) are connected with each other and are caused by the anomalous proximity effect. The authors of Ref. [1] used essentially the same method of the quasiclassical Green's functions for the calculation of the DOS (the Usadel equation), but they employed another method (the Landauer formula) for the calculation of the conductance. The results of the work [1] coincide with that obtained in Ref. [2], but the interpretation of the subgap conductance is close to that given in Ref. [11] and is complimentary to ours.

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